

Sample &

Buy





#### uA741

SLOS094E - NOVEMBER 1970-REVISED JANUARY 2015

# µA741 General-Purpose Operational Amplifiers

Technical

Documents

### 1 Features

- Short-Circuit Protection
- Offset-Voltage Null Capability
- Large Common-Mode and Differential Voltage
  Ranges
- No Frequency Compensation Required
- No Latch-Up

### 2 Applications

- DVD Recorders and Players
- Pro Audio Mixers

### 3 Description

The  $\mu$ A741 device is a general-purpose operational amplifier featuring offset-voltage null capability.

The high common-mode input voltage range and the absence of latch-up make the amplifier ideal for voltage-follower applications. The device is short-circuit protected and the internal frequency compensation ensures stability without external components. A low value potentiometer may be connected between the offset null inputs to null out the offset voltage as shown in Figure 11.

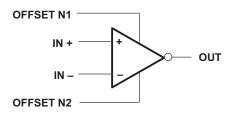
The  $\mu$ A741C device is characterized for operation from 0°C to 70°C. The  $\mu$ A741M device (obsolete) is characterized for operation over the full military temperature range of –55°C to 125°C.

Device	Inform	hation <sup>(1)</sup>
--------	--------	-----------------------

PART NUMBER	PACKAGE (PIN)	BODY SIZE (NOM)
	SOIC (8)	4.90 mm × 3.91 mm
μA741x	PDIP (8)	9.81 mm × 6.35 mm
	SO (8)	6.20 mm × 5.30 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### **4** Simplified Schematic



# **Table of Contents**

1	Feat	tures 1
2	Арр	lications 1
3	Des	cription 1
4	Sim	plified Schematic1
5	Rev	ision History 2
6	Pin	Configurations and Functions 3
7	Spe	cifications 4
	7.1	Absolute Maximum Ratings 4
	7.2	Recommended Operating Conditions 4
	7.3	Electrical Characteristics µA741C, µA741M 5
	7.4	Electrical Characteristics µA741Y 6
	7.5	Switching Characteristics µA741C, µA741M6
	7.6	Switching Characteristics µA741Y 6
	7.7	Typical Characteristics 7
8	Deta	ailed Description
	8.1	Overview

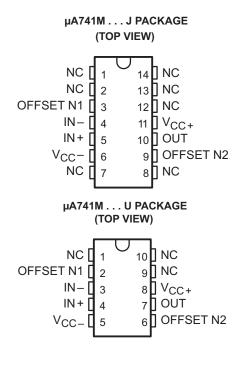
	8.2	Functional Block Diagram	9
	8.3	Feature Description	10
	8.4	Device Functional Modes	10
	8.5	µA741Y Chip Information	10
9	App	lication and Implementation	11
	9.1	Application Information	11
	9.2	Typical Application	
10	Pow	ver Supply Recommendations	13
11	Lay	out	13
	11.1	Layout Guidelines	13
	11.2	Layout Example	13
12	Dev	ice and Documentation Support	15
	12.1	Trademarks	15
	12.2	Electrostatic Discharge Caution	15
	12.3	Glossary	15
13	Мес	hanical, Packaging, and Orderable	
		rmation	15

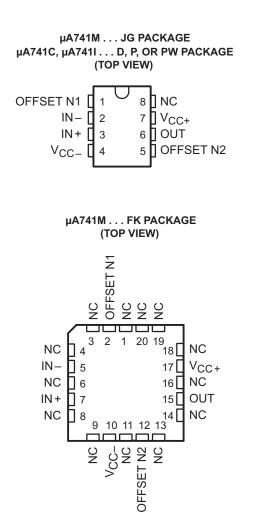
# 5 Revision History

Cł	nanges from Revision D (February 2014) to Revision E	Page
•	Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.	1
•	Moved Typical Characteristics into Specifications section.	7
Cł	nanges from Revision C (January 2014) to Revision D	Page
•	Fixed Typical Characteristics graphs to remove extra lines.	7
Cł	nanges from Revision B (September 2000) to Revision C	Page
•	Updated document to new TI data sheet format - no specification changes.	
•	Deleted Ordering Information table.	1



### 6 Pin Configurations and Functions





NC – No internal connection

#### Pin Functions

			PIN			
NAME	J	JG, D, P, or PW	U	FK	TYPE	DESCRIPTION
IN+	5	3	4	7	Ι	Noninverting input
IN-	4	2	3	5	Ι	Inverting input
NC	1, 2, 8, 12, 13, 14	8	1, 9, 10	1,3,4,6,8,9,11,13,1 4,16,18,19,20	_	Do not connect
OFFSET N1	3	1	2	2	Ι	External input offset voltage adjustment
OFFSET N2	9	5	6	12	Ι	External input offset voltage adjustment
OUT	10	6	7	15	0	Output
V <sub>CC</sub> +	11	7	8	17	_	Positive supply
V <sub>CC</sub> -	6	4	5	10		Negative supply

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over virtual junction temperature range (unless otherwise noted)<sup>(1)</sup>

			μA741C	:	μA741M	UNIT			
			MIN	MAX	MIN	MAX	UNIT		
$V_{CC}$	Supply voltage <sup>(2)</sup>		-18	18	-22	22	С		
$V_{\text{ID}}$	Differential input voltage <sup>(3)</sup>		-15	15	-30	30	V		
VI	Input voltage, any input <sup>(2)(4)</sup>		-15	15	-15	15	V		
	Voltage between offset null (either OFFSET N1 or OF	-15	15	-0.5	0.5	V			
	Duration of output short circuit <sup>(5)</sup>		Unlimited						
	Continuous total power dissipation		S	ee Table 1					
T <sub>A</sub>	Operating free-air temperature range		0	70	-55	125	°C		
	Case temperature for 60 seconds	FK package	N/A	N/A		260	°C		
	Lead temperature 1.6 mm (1/16 inch) from case for 60 seconds	J, JG, or U package	N/A	N/A		300	°C		
	Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds		260	N/A	N/A	°C			
T <sub>stg</sub>	Storage temperature range		-65	150	65	150	°C		

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values, unless otherwise noted, are with respect to the midpoint between  $V_{CC+}$  and  $V_{CC-}$ .

(3) Differential voltages are at IN+ with respect to IN -.

(4) The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.

(5) The output may be shorted to ground or either power supply. For the μA741M only, the unlimited duration of the short circuit applies at (or below) 125°C case temperature or 75°C free-air temperature.

### 7.2 Recommended Operating Conditions

			MIN	MAX	UNIT
$V_{CC+}$	Overslavella				V
V <sub>CC</sub> -	Supply voltage		-5	-15	v
-		µA741C	0	70	*
IA	Operating free-air temperature	µA741M	-55	125	°C

### Table 1. Dissipation Ratings Table

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T <sub>A</sub>	TA = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D	500 mW	5.8 mW/°C	64°C	464 mW	377 mW	N/A
FK	500 mW	11.0 mW/°C	105°C	500 mW	500 mW	275 mW
J	500 mW	11.0 mW/°C	105°C	500 mW	500 mW	275 mW
JG	500 mW	8.4 mW/°C	90°C	500 mW	500 mW	210 mW
Р	500 mW	N/A	N/A	500 mW	500 mW	N/A
PS	525 mW	4.2 mW/°C	25°C	336 mW	N/A	N/A
U	500 mW	5.4 mW/°C	57°C	432 mW	351 mW	135 mW



### 7.3 Electrical Characteristics µA741C, µA741M

at specified virtual junction temperature,  $V_{CC\pm} = \pm 15 \text{ V}$  (unless otherwise noted)

	BABAMETER	TEST CONDITIONS T <sub>A</sub> <sup>(1)</sup>		μA741C			μA741M			UNIT
	PARAMETER	TEST CONDITIONS	IA.,,	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
		N 0	25°C		1	6		1	5	
V <sub>IO</sub>	Input offset voltage	$V_0 = 0$	Full range			7.5		±15	6	mV
$\Delta V_{IO(adj)}$	Offset voltage adjust range	V <sub>O</sub> = 0	25°C		±15			20	200	mV
I <sub>IO</sub>	Input offset current	N 0	25°C		20	200			500	~ ^
	input onset current	$V_0 = 0$	Full range			300			500	nA
	Input biog ourrent	$\mathcal{V} = 0$	25°C		80	500		80	500	۳Å
I <sub>IB</sub>	Input bias current	$V_0 = 0$	Full range			800			1500	nA
V <sub>ICR</sub>	Common-mode input voltage range		25°C	±12	±13		±12	±13		V
	Common-mode input voltage range		Full range	±12			±12			v
		$R_L = 10 \ k\Omega$	25°C	±12	±14		±12	±14		V
	Maximum peak output voltage swing	$R_L \ge 10 \ k\Omega$	Full range	±12			±12			
V <sub>OM</sub>		$R_L = 2 k\Omega$	25°C	±10			±10	±13		
		$R_L \ge 2k\Omega$	Full range	±10			±10			
٨	Large-signal differential voltage	$R_L \ge 2k\Omega$	25°C	20	200		50	200		V/mV
A <sub>VD</sub>	amplification	$V_0 = \pm 10 V$	Full range	15			25			V/IIIV
r <sub>i</sub>	Input resistance		25°C	0.3	2		0.3	2		MΩ
r <sub>o</sub>	Output resistance	$V_{O} = 0$ , See <sup>(2)</sup>	25°C		75			75		Ω
Ci	Input capacitance		25°C		1.4			1.4		pF
CMRR	Common-mode rejection ratio		25°C	70	90		70	90		dB
CIVIKK	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$	Full range	70			70			uБ
k	Supply voltage sensitivity ( $\Delta V_{IO} / \Delta V_{CC}$ )	$V_{CC} = \pm 9 \text{ V to } \pm 15 \text{ V}$	25°C		30	150		30	150	μV/V
k <sub>SVS</sub>	Supply voltage sensitivity ( $\Delta v_{IO}/\Delta v_{CC}$ )	$v_{CC} = \pm 9 v (0 \pm 15 v)$	Full range			150			150	μν/ν
l <sub>os</sub>	Short-circuit output current		25°C		±25	±40		±25	±40	mA
	Supply current	V = 0 No load	25°C		1.7	2.8		1.7	2.8	m۸
I <sub>CC</sub>		$V_0 = 0$ , No load	Full range			3.3			3.3	mA
D	Total power dissipation	$V_{0} = 0$ . No load	25°C		50	85		50	85	mW
P <sub>D</sub>	Total power dissipation		Full range			100			100	TIVV

(1) All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range for the  $\mu$ A741C is 0°C to 70°C and the  $\mu$ A741M is -55°C to 125°C.

(2) This typical value applies only at frequencies above a few hundred hertz because of the effects of drift and thermal feedback.

RUMENTS

XAS

## 7.4 Electrical Characteristics µA741Y

at specified virtual junction temperature, V<sub>CC±</sub> = ±15 V, T<sub>A</sub> = 25°C (unless otherwise noted)<sup>(1)</sup>

	DADAMETED	TEST CONDITIONS	-	JA741Y			
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V <sub>IO</sub>	Input offset voltage	V <sub>O</sub> = 0		1	5	mV	
$\Delta V_{IO(adj)}$	Offset voltage adjust range	V <sub>O</sub> = 0		±15		mV	
I <sub>IO</sub>	Input offset current	V <sub>O</sub> = 0		20	200	nA	
I <sub>IB</sub>	Input bias current	V <sub>O</sub> = 0		80	500	nA	
VICR	Common-mode input voltage range		±12	±13		V	
		R <sub>L</sub> = 10 kΩ ±12		±14			
V <sub>OM</sub>	Maximum peak output voltage swing	$R_L = 2 k\Omega$	±10	±13		V	
A <sub>VD</sub>	Large-signal differential voltage amplification	$R_L \ge 2k\Omega$	20	200		V/mV	
r <sub>i</sub>	Input resistance		0.3	2		MΩ	
r <sub>o</sub>	Output resistance	$V_0 = 0$ , See <sup>(1)</sup>		75		Ω	
Ci	Input capacitance			1.4		pF	
CMRR	Common-mode rejection ratio	V <sub>IC</sub> = V <sub>ICRmin</sub>	70	90		dB	
k <sub>SVS</sub>	Supply voltage sensitivity ( $\Delta V_{IO} / \Delta V_{CC}$ )	$V_{CC} = \pm 9 \text{ V to } \pm 15 \text{ V}$		30	150	μV/V	
I <sub>OS</sub>	Short-circuit output current			±25	±40	mA	
I <sub>cc</sub>	Supply current	V <sub>O</sub> = 0, No load		1.7	2.8	mA	
P <sub>D</sub>	Total power dissipation	V <sub>O</sub> = 0, No load		50	85	mW	

(1) This typical value applies only at frequencies above a few hundred hertz because of the effects of drift and thermal feedback.

## 7.5 Switching Characteristics µA741C, µA741M

over operating free-air temperature range, V<sub>CC±</sub> = ±15 V, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	μA741C			μ	UNIT		
	FARAIVIETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
t <sub>r</sub>	Rise time	$V_{I} = 20 \text{ mV}, R_{L} = 2 \text{ k}\Omega,$		0.3			0.3		μs
	Overshoot factor	$\dot{C}_{L} = 100 \text{ pF}, \bar{S}ee \text{ Figure 1}$		5%			5%		_
SR	Slew rate at unity gain			0.5			0.5		V/µs

## 7.6 Switching Characteristics µA741Y

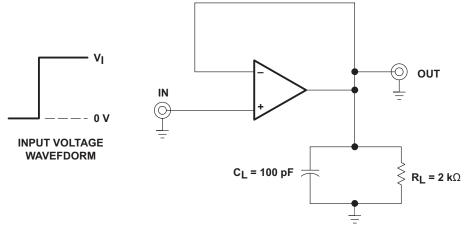
over operating free-air temperature range,  $V_{CC\pm} = \pm 15 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	μΑ741Y			
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>r</sub>	Rise time	$V_{I} = 20 \text{ mV}, R_{L} = 2 \text{ k}\Omega,$		0.3		μs
	Overshoot factor	$C_{L} = 100 \text{ pF}, \text{ See Figure 1}$		5%		_
SR	Slew rate at unity gain			0.5		V/µs

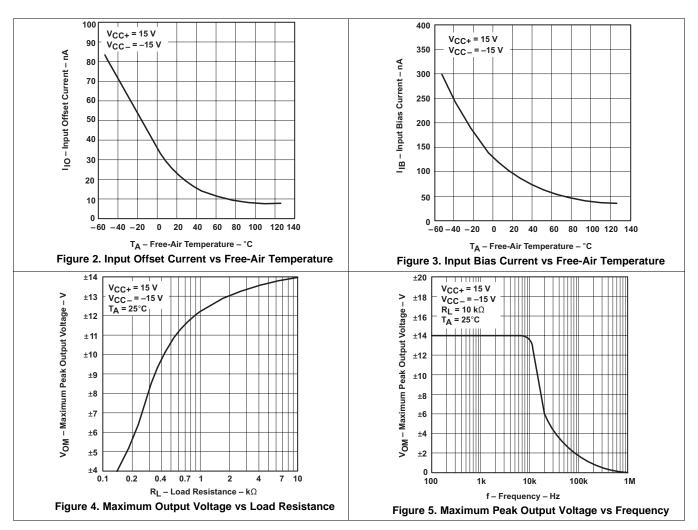


### 7.7 Typical Characteristics

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

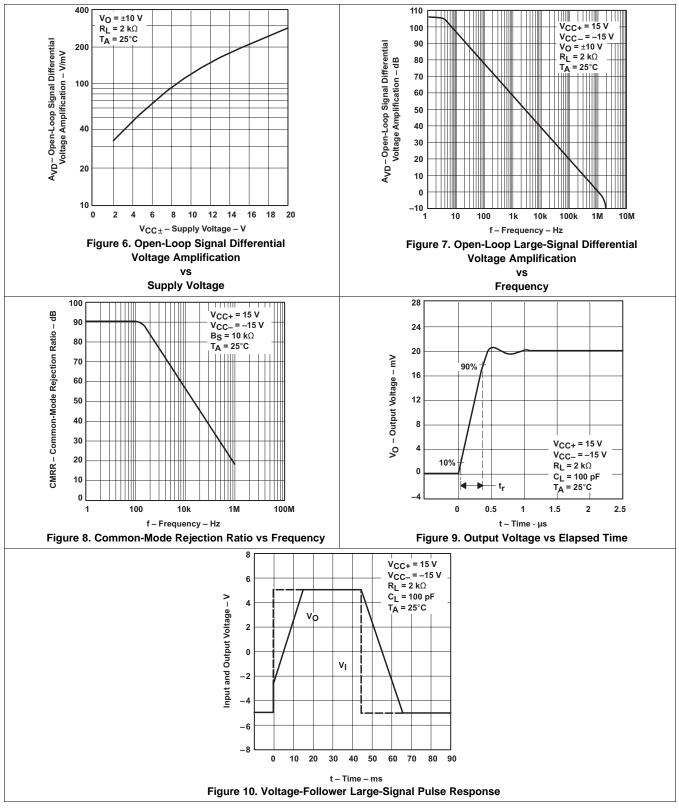


TEST CIRCUIT Figure 1. Rise Time, Overshoot, and Slew Rate



## **Typical Characteristics (continued)**

Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.





### 8 Detailed Description

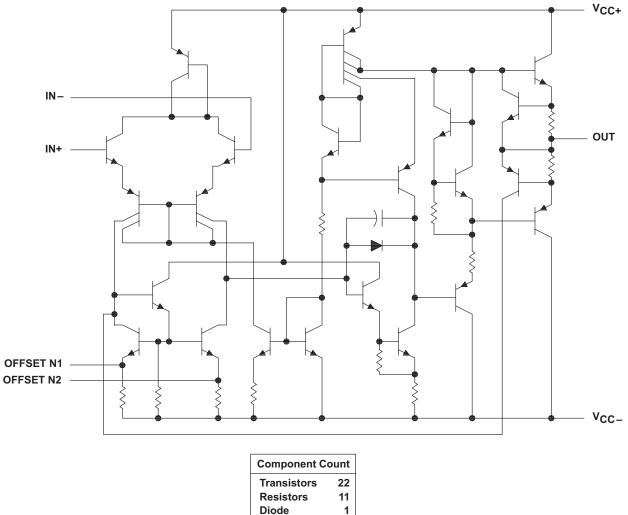
#### 8.1 Overview

The µA741 device is a general-purpose operational amplifier featuring offset-voltage null capability.

The high common-mode input voltage range and the absence of latch-up make the amplifier ideal for voltagefollower applications. The device is short-circuit protected and the internal frequency compensation ensures stability without external components. A low value potentiometer may be connected between the offset null inputs to null out the offset voltage as shown in Figure 11.

The  $\mu$ A741C device is characterized for operation from 0°C to 70°C. The  $\mu$ A741M device (obsolete) is characterized for operation over the full military temperature range of –55°C to 125°C.

#### 8.2 Functional Block Diagram



Biodo	
Capacitor	

1



#### 8.3 Feature Description

#### 8.3.1 Offset-Voltage Null Capability

The input offset voltage of operational amplifiers (op amps) arises from unavoidable mismatches in the differential input stage of the op-amp circuit caused by mismatched transistor pairs, collector currents, currentgain betas ( $\beta$ ), collector or emitter resistors, etc. The input offset pins allow the designer to adjust for these mismatches by external circuitry. See the *Application and Implementation* section for more details on design techniques.

#### 8.3.2 Slew Rate

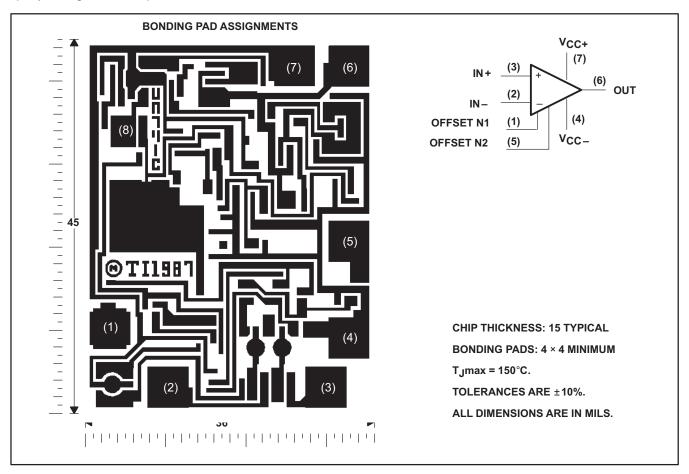
The slew rate is the rate at which an operational amplifier can change its output when there is a change on the input. The  $\mu$ A741 has a 0.5-V/ $\mu$ s slew rate. Parameters that vary significantly with operating voltages or temperature are shown in the *Typical Characteristics* graphs.

#### 8.4 Device Functional Modes

The µA741 is powered on when the supply is connected. It can be operated as a single supply operational amplifier or dual supply amplifier depending on the application.

### 8.5 µA741Y Chip Information

This chip, when properly assembled, displays characteristics similar to the  $\mu$ A741C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.





### 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

The input offset voltage of operational amplifiers (op amps) arises from unavoidable mismatches in the differential input stage of the op-amp circuit caused by mismatched transistor pairs, collector currents, currentgain betas ( $\beta$ ), collector or emitter resistors, etc. The input offset pins allow the designer to adjust for these mismatches by external circuitry. These input mismatches can be adjusted by putting resistors or a potentiometer between the inputs as shown in Figure 13. A potentiometer can be used to fine tune the circuit during testing or for applications which require precision offset control. More information about designing using the input-offset pins, see the application note *Nulling Input Offset Voltage of Operational Amplifiers*, SLOA045.

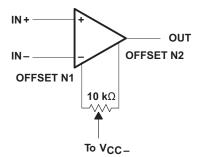


Figure 11. Input Offset Voltage Null Circuit

### 9.2 Typical Application

The voltage follower configuration of the operational amplifier is used for applications where a weak signal is used to drive a relatively high current load. This circuit is also called a buffer amplifier or unity gain amplifier. The inputs of an operational amplifier have a very high resistance which puts a negligible current load on the voltage source. The output resistance of the operational amplifier is almost negligible, so it can provide as much current as necessary to the output load.

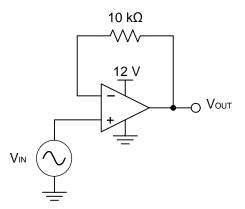


Figure 12. Voltage Follower Schematic

#### 9.2.1 Design Requirements

- Output range of 2 V to 11.5 V
- Input range of 2 V to 11.5 V

TEXAS INSTRUMENTS

www.ti.com

#### **Typical Application (continued)**

Resistive feedback to negative input

#### 9.2.2 Detailed Design Procedure

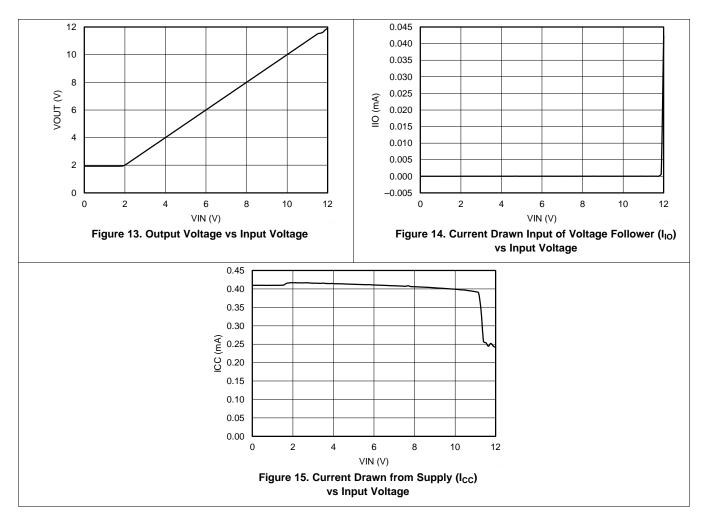
#### 9.2.2.1 Output Voltage Swing

The output voltage of an operational amplifier is limited by its internal circuitry to some level below the supply rails. For this amplifier, the output voltage swing is within  $\pm 12$  V, which accommodates the input and output voltage requirements.

#### 9.2.2.2 Supply and Input Voltage

For correct operation of the amplifier, neither input must be higher than the recommended positive supply rail voltage or lower than the recommended negative supply rail voltage. The chosen amplifier must be able to operate at the supply voltage that accommodates the inputs. Because the input for this application goes up to 11.5 V, the supply voltage must be 12 V. Using a negative voltage on the lower rail rather than ground allows the amplifier to maintain linearity for inputs below 2 V.

#### 9.2.3 Application Curves for Output Characteristics





### **10** Power Supply Recommendations

The  $\mu$ A741 is specified for operation from ±5 to ±15 V; many specifications apply from 0°C to 70°C. The *Typical Characteristics* section presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

### CAUTION

Supply voltages larger than ±18 V can permanently damage the device (see the *Absolute Maximum Ratings*).

Place 0.1-µF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies. For more detailed information on bypass capacitor placement, refer to the *Layout Guidelines*.

### 11 Layout

### 11.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low impedance power sources local to the analog circuitry.
  - Connect low-ESR, 0.1-µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, refer to *Circuit Board Layout Techniques*, SLOA089.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in *Layout Example*.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

### 11.2 Layout Example

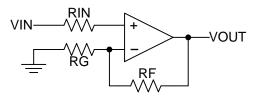


Figure 16. Operational Amplifier Schematic for Noninverting Configuration

TEXAS INSTRUMENTS

www.ti.com

## Layout Example (continued)

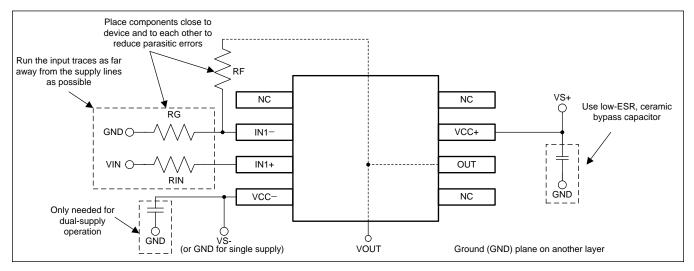


Figure 17. Operational Amplifier Board Layout for Noninverting Configuration



## **12 Device and Documentation Support**

### 12.1 Trademarks

All trademarks are the property of their respective owners.

### 12.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.



10-Jun-2014

# PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
UA741CD	(1) ACTIVE	SOIC	Drawing	8	75	(2) Green (RoHS & no Sb/Br)	(6) CU NIPDAU	(3) Level-1-260C-UNLIM	0 to 70	(4/5) UA741C	Samples
UA741CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	UA741C	Samples
UA741CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	UA741C	Samples
UA741CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	UA741C	Samples
UA741CJG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	0 to 70		
UA741CJG4	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	0 to 70		
UA741CP	ACTIVE	PDIP	Ρ	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	UA741CP	Samples
UA741CPE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	UA741CP	Samples
UA741CPSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	U741	Samples
UA741CPSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	U741	Samples
UA741MFKB	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI	-55 to 125		
UA741MJ	OBSOLETE	CDIP	J	14		TBD	Call TI	Call TI	-55 to 125		
UA741MJB	OBSOLETE	CDIP	J	14		TBD	Call TI	Call TI	-55 to 125		
UA741MJG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		
UA741MJGB	OBSOLETE	E CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.



10-Jun-2014

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and package die adhesive used between the die adhesive

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

### TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All c	dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	UA741CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
	UA741CPSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

# PACKAGE MATERIALS INFORMATION

17-Feb-2014



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UA741CDR	SOIC	D	8	2500	340.5	338.1	20.6
UA741CPSR	SO	PS	8	2000	367.0	367.0	38.0

# **MECHANICAL DATA**

MCER001A - JANUARY 1995 - REVISED JANUARY 1997



#### **CERAMIC DUAL-IN-LINE**



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8



J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N\*\*) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



### **MECHANICAL DATA**

## PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.





NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ctivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2015, Texas Instruments Incorporated